

## Correlation between leakage current and charge gain in irradiated LGADs

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The gain of charge in LGADs (GQ) and the increase of the leakage current (GI) with respect to the generation current ( $I_{gen}$ ) are different, due to charge screening of the electric field in the gain layer, trapping-detrapping process and also possible other effects. A TCT was used to simultaneously measure GI and GQ in USFD-FBK4.0 prototypes. A special structure with PIN and LGADs very close together was used. The absolute charge measurements were assured with the use of beam-monitoring circuit. The difference between GI and GQ was found to become substantial at higher fluences and bias voltages.

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